

IRF7464

IRF7464 Information



Part Number	IRF7464
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Description	MOSFET N-CH 200V 1.2A 8-SOIC
Package	8-SOIC (0.154", 3.90mm Width)
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

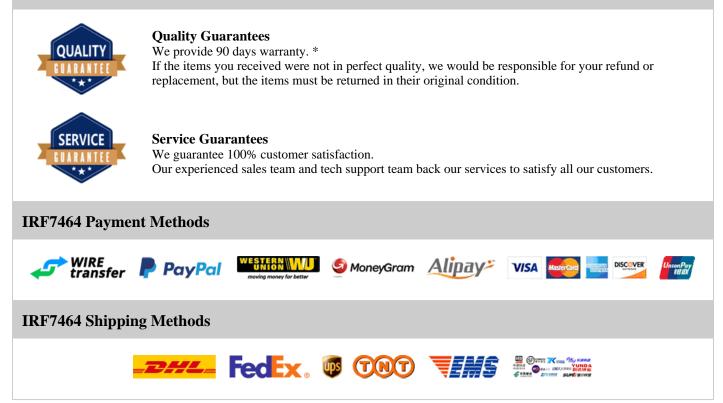
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRF7464 Specifications

Manufacturer Part Number	IRF7464
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-SOIC (0.154", 3.90mm Width)
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	1.2A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	280pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	2.5W (Ta)
Rds On (Max) @ Id, Vgs	730 mOhm @ 720mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-SO
Package / Case	8-SOIC (0.154", 3.90mm Width)
	Report errors?

IRF7464 Guarantees



If you have any question about IRF7464, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com